TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7MBD3245AFK

#### Octal Bus Switch

The TC7MBD3245AFK provides eight bits of high-speed TTL-compatible bus switching in a standard '245 device pinout. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

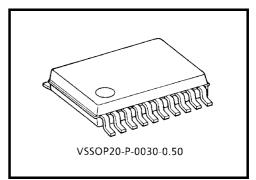
The device is organized as one 8-bit switch. When output enable  $(\overline{OE})$  is low, the switch is on and port A is connected to port B. When  $\overline{OE}$  is high, the switch is open and a high-impedance state exists between the two ports.

The device is enable to realize the shift of signal level from 5 V to 3.3 V.

All inputs are equipped with protection circuits against static discharge.

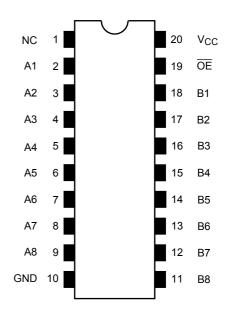


- Operating voltage: V<sub>CC</sub> = 4.5~5.5 V
- High speed:  $t_{pd} = 0.32 \text{ ns} (\text{max})$
- Low on resistance:  $R_{ON} = 5 \Omega$  (typ.)
- ESD performance: Human body model >  $\pm 2000 \text{ V}$ Machine model >  $\pm 200 \text{ V}$
- Compatible with TTL outputs (control inputs)
- Low Power Dissipation: Icc =  $10 \ \mu A \ (max.)$
- Package: VSSOP (US20)
- Pin compatible with the 74xx245 type.
- Functionally equivalent to (FST/CBT) 3245.



Weight: 0.03 g (typ.)

#### Pin Assignment (top view)



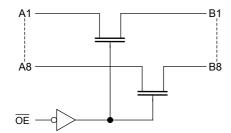
NC-No Internal Connection

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## Truth Table

Inputs	Function		
OE	T unction		
L	A port = B port		
Н	Disconnect		

# System Diagram



# Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply range	V <sub>CC</sub>	-0.5~7.0	V
DC input voltage	V <sub>IN</sub>	-0.5~7.0	V
DC switch voltage	VS	-0.5~7.0	V
Input diode current	I <sub>IK</sub>	-50	mA
Continuous channel circuit	IS	128	mA
Power dissipation	PD	180	mW
DC V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA
Storage temperature	T <sub>stg</sub>	-65~150	°C

# **Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	4.5~5.5	V
Input voltage	V <sub>IN</sub>	0~5.5	V
Switch voltage	VS	0~5.5	V
Operating temperature	T <sub>opr</sub>	-40~85	°C
Input rise and fall time	dt/dv	0~10	ns/V

#### **Electrical Characteristics**

#### DC Characteristics (Ta = -40~85°C)

Charac	teristics	Symbol	Test Co	ndition	V <sub>CC</sub> (V)	Min	Typ. (Note 1)	Max	Unit						
Input voltage	"H" level	VIH		-	4.5~5.5	2.0	—	_	V						
Input voltage	"L" level	V <sub>IL</sub>		-	4.5~5.5	_		0.8	v						
Llich lovel outr	ut voltogo				4.75	2.3	2.8	3.2							
High-level outp	(Note 2)	VOH	IOH=-1μA		5.0	2.5	3.0	3.4	V						
	(NOLE 2)			$V_{IS} = V_{CC}$		2.7	3.2	3.6							
Input leakage of	current	I <sub>IN</sub>	V <sub>IN</sub> = 0~5.5 V		4.5~5.5		—	±1.0	μA						
Power off leaka	age current	IOFF	A, B, $\overline{OE} = 0 \sim 5.5 \text{ V}$		0	_	—	±1.0	μA						
Off-STATE lea (switch off)	kage current	I <sub>SZ</sub>	A, B = $0 \sim 5.5 \text{ V}$ , $\overline{\text{OE}}$ =	- V <sub>CC</sub>	4.5~5.5	_		±1.0	μA						
				h. 64 mA	4.5	_	5	9							
					V <sub>IS</sub> = 0 V		N 0.V			I <sub>IS</sub> = 64 mA	4.75		5	8	
ON resistance		(Note 3)	VIS = 0 V	ha 20 mA	4.5		5	9	Ω						
	(Note 3)			I <sub>IS</sub> = 30 mA	4.75		5	8	52						
			V 0.0.V 1 45		4.5	4.5 —	35	65							
			$V_{IS} = 2.3 \text{ V}, I_{IS} = 15 \text{ m}$	A	4.75		35	50							
Quiescent sup	oly current	ICC	VIN = VCC or GND,I <sub>OUT</sub> = 0		5.5		_	10	μA						
Increase in I <sub>CC</sub>	; per input	$\Delta I_{CC}$	V <sub>IN</sub> = 3.4 V (one input)		5.5	_	_	2.5	mA						

Note 1: Typical values are at  $V_{CC} = 5 V$ , Ta =  $25^{\circ}C$ .

- Note 2: It recommends that this device uses Pull-up resistance when adding and using resistance for an output terminal. Since it couses to drop a VOH voltage level when using Pull-down resistance for an output terminal.
- Note 3: Measured by the voltage drop between A and B pins at the indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

#### AC Characteristics (Ta = -40~85°C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2 (Note 4)	4.5		0.32	ns
(bus to bus)	t <sub>pHL</sub>		4.5		0.32	115
Output enable time	t <sub>pZL</sub>	Figure 1, Figure 3	4.5		7.0	ns
	t <sub>pZH</sub>		4.0		7.0	115
Output disable time	t <sub>pLZ</sub>	Figure 1, Figure 3	4.5		7.0	ns
	t <sub>pHZ</sub>		4.5		7.0	115

Note 4: The propagation delay time is calculated by the RC (on-resistance and load capacitance) time constant.

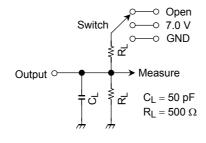
#### **Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Control pin input capacitance	C <sub>IN</sub>	(Note 5)	5.0	3	pF
Switch terminal capacitance	C <sub>I/O</sub>	$\overline{OE} = V_{CC}$ (Note 5)	5.0	10	pF

Note 5: This parameter is guaranteed by design.

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### **AC Test Circuit**



Paramenter	Switch
t <sub>pLH</sub> , t <sub>pHL</sub>	Open
t <sub>pLZ</sub> , t <sub>pZL</sub>	7.0 V
t <sub>pHZ</sub> , t <sub>pZH</sub>	GND



#### **AC Waveform**

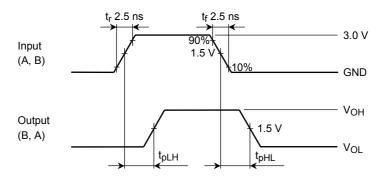
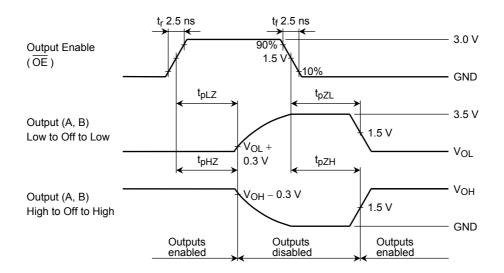
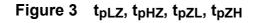


Figure 2 t<sub>pLH</sub>, t<sub>pHL</sub>





## V<sub>OH</sub> – V<sub>CC</sub> Characteristics (typ.)

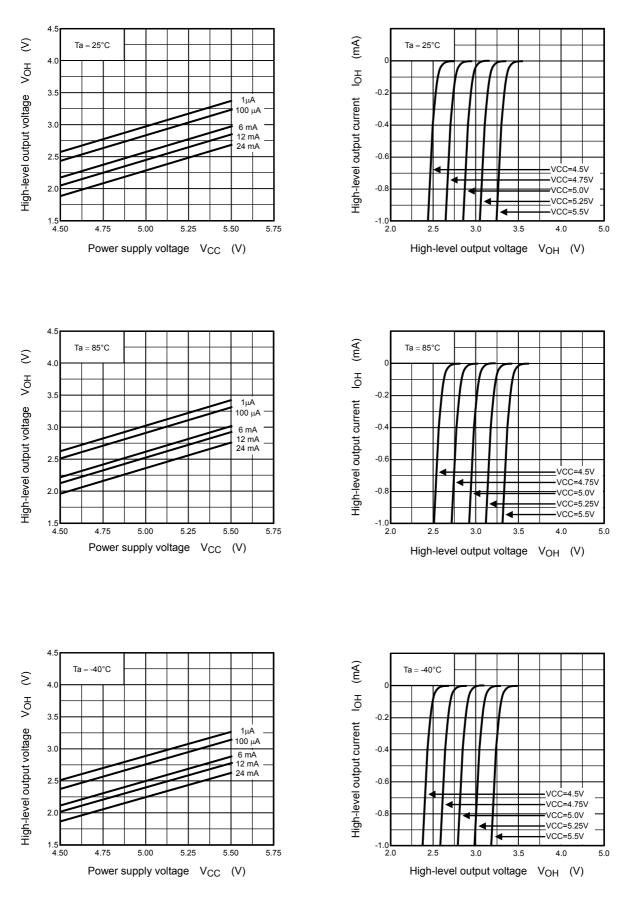


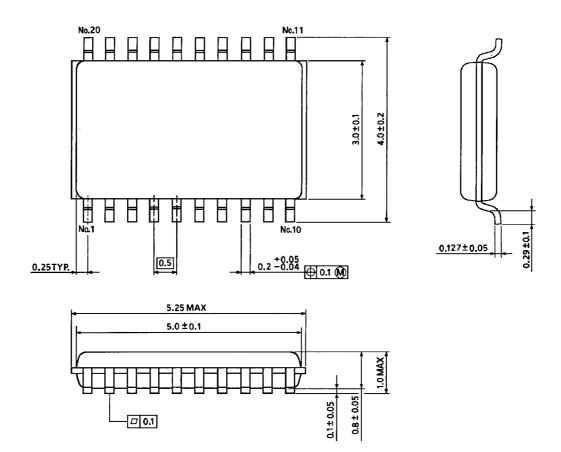
Figure 4



#### **Package Dimensions**

VSSOP20-P-0030-0.50

Unit : mm



Weight: 0.03 g (typ.)

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